

BFQ19

NPN 5 GHz wideband transistor

Rev. 03 — 28 September 2007

Product data sheet

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NXP Semiconductors

NPN 5 GHz wideband transistor

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DESCRIPTION

NPN transistor in a SOT89 plastic envelope intended for application in thick and thin-film circuits. It is primarily intended for use in UHF and microwave amplifiers such as in aerial amplifiers, radar systems, oscilloscopes, spectrum analysers etc.

The transistor features very low intermodulation distortion and high power gain. Due to its very high transition frequency, it also has excellent wideband properties and low noise up to high frequencies.

PINNING

PIN	DESCRIPTION
Code: FB	
1	emitter
2	collector
3	base

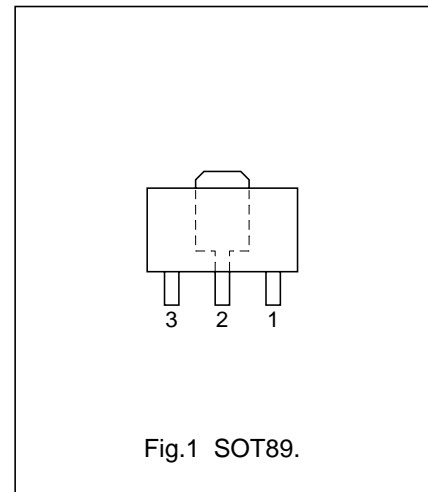


Fig.1 SOT89.

QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS	TYP.	MAX.	UNIT
V_{CEO}	collector-emitter voltage	open base	–	15	V
I_C	DC collector current		–	100	mA
P_{tot}	total power dissipation	up to $T_s = 145\text{ °C}$ (note 1)	–	1	W
f_T	transition frequency	$I_C = 50\text{ mA}$; $V_{CE} = 10\text{ V}$; $f = 500\text{ MHz}$; $T_j = 25\text{ °C}$	5.5	–	GHz
C_{re}	feedback capacitance	$I_C = 10\text{ mA}$; $V_{CE} = 10\text{ V}$; $f = 1\text{ MHz}$; $T_{amb} = 25\text{ °C}$	1.3	–	pF
F	noise figure	$I_C = 50\text{ mA}$; $V_{CE} = 10\text{ V}$; $Z_s = \text{opt.}$; $f = 500\text{ MHz}$; $T_{amb} = 25\text{ °C}$	3.3	–	dB

LIMITING VALUES

In accordance with the Absolute Maximum System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V_{CBO}	collector-base voltage	open emitter	–	20	V
V_{CEO}	collector-emitter voltage	open base	–	15	V
V_{EBO}	emitter-base voltage	open collector	–	3.3	V
I_C	DC collector current		–	100	mA
I_{CM}	peak collector current	$f > 1\text{ MHz}$	–	150	mA
P_{tot}	total power dissipation	up to $T_s = 145\text{ °C}$ (note 1)	–	1	W
T_{stg}	storage temperature		–65	150	°C
T_j	junction temperature		–	175	°C

Note

- T_s is the temperature at the soldering point of the collector tab.

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THERMAL RESISTANCE

SYMBOL	PARAMETER	CONDITIONS	THERMAL RESISTANCE
$R_{th\ j-s}$	thermal resistance from junction to soldering point	up to $T_s = 145\text{ °C}$ (note 1)	30 K/W

Note

- T_s is the temperature at the soldering point of the collector tab.

CHARACTERISTICS

$T_j = 25\text{ °C}$ unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
I_{CBO}	collector cut-off current	$I_E = 0; V_{CB} = 10\text{ V}$	–	–	100	nA
h_{FE}	DC current gain	$I_C = 70\text{ mA}; V_{CE} = 10\text{ V}$	25	80	–	
C_c	collector capacitance	$I_E = i_e = 0; V_{CB} = 10\text{ V}; f = 1\text{ MHz}$	–	1.6	–	pF
C_e	emitter capacitance	$I_C = i_c = 0; V_{EB} = 0.5\text{ V}; f = 1\text{ MHz}$	–	5	–	pF
C_{re}	feedback capacitance	$I_C = 10\text{ mA}; V_{CE} = 10\text{ V}; f = 1\text{ MHz}; T_{amb} = 25\text{ °C}$	–	1.3	–	pF
f_T	transition frequency	$I_C = 70\text{ mA}; V_{CE} = 10\text{ V}; f = 500\text{ MHz}$	4.4	5.5	–	GHz
G_{UM}	maximum unilateral power gain (note 1)	$I_C = 50\text{ mA}; V_{CE} = 10\text{ V}; f = 500\text{ MHz}; T_{amb} = 25\text{ °C}$	–	11.5	–	dB
		$I_C = 50\text{ mA}; V_{CE} = 10\text{ V}; f = 800\text{ MHz}; T_{amb} = 25\text{ °C}$	–	7.5	–	dB
F	noise figure	$I_C = 50\text{ mA}; V_{CE} = 10\text{ V}; Z_s = \text{opt.}; f = 500\text{ MHz}; T_{amb} = 25\text{ °C}$	–	3.3	–	dB

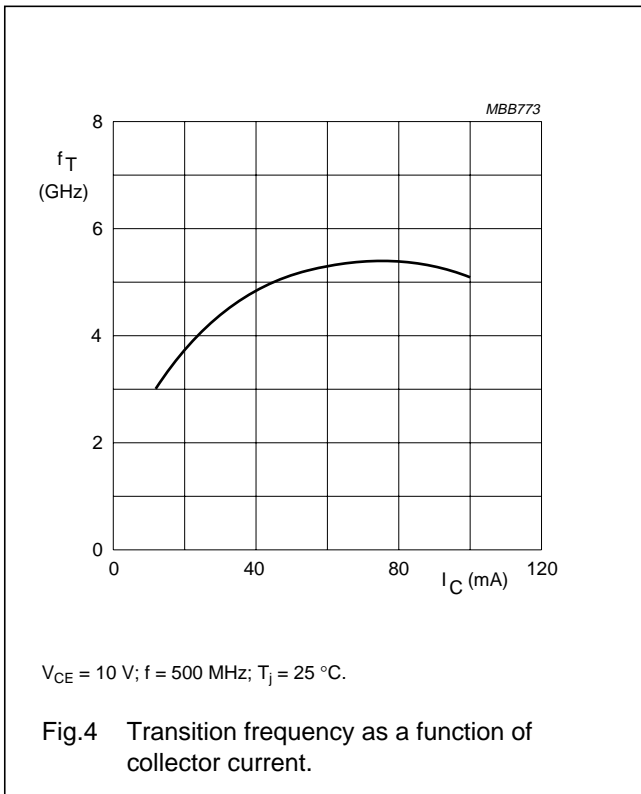
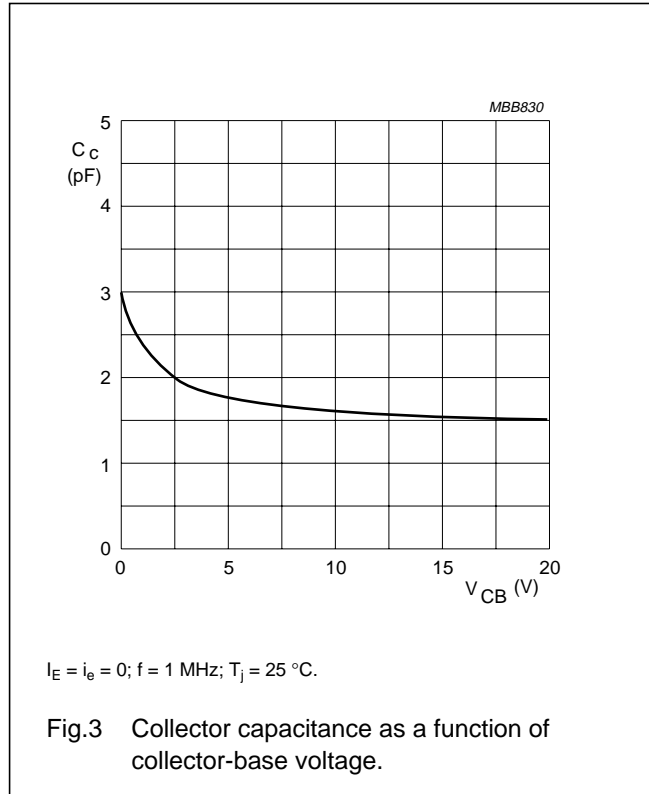
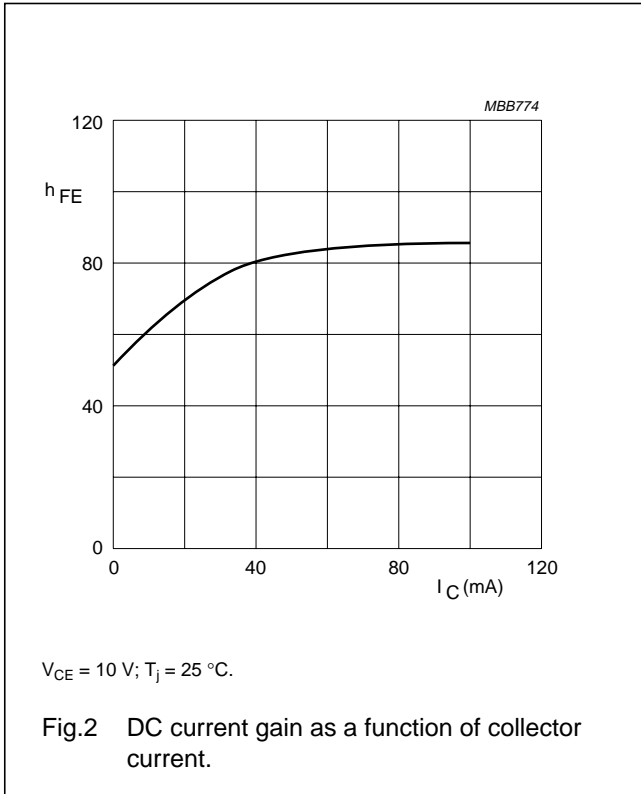
Note

- G_{UM} is the maximum unilateral power gain, assuming S_{12} is zero and

$$G_{UM} = 10 \log \left(\frac{|S_{21}|^2}{(1 - |S_{11}|^2)(1 - |S_{22}|^2)} \right) \text{ dB.}$$

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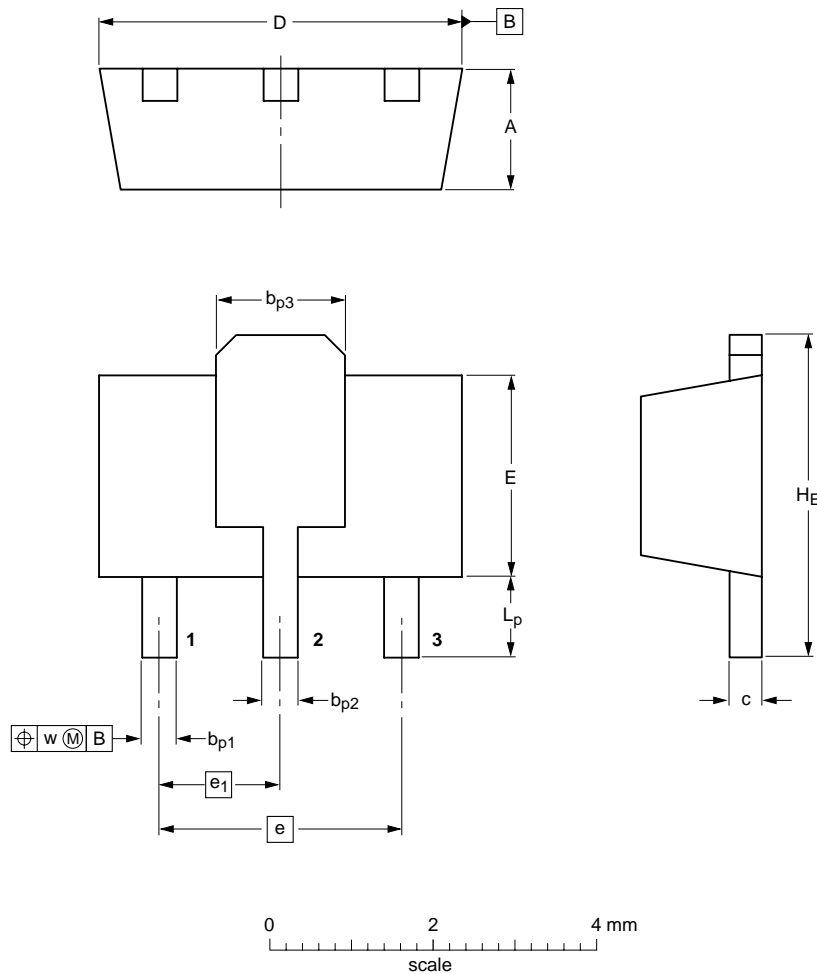
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PACKAGE OUTLINE

Plastic surface-mounted package; collector pad for good heat transfer; 3 leads

SOT89



DIMENSIONS (mm are the original dimensions)

UNIT	A	b _{p1}	b _{p2}	b _{p3}	c	D	E	e	e ₁	H _E	L _p	w
mm	1.6	0.48	0.53	1.8	0.44	4.6	2.6	3.0	1.5	4.25	1.2	0.13
	1.4	0.35	0.40	1.4	0.23	4.4	2.4					

OUTLINE VERSION	REFERENCES			EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	JEITA		
SOT89		TO-243	SC-62		06-03-16 06-08-29

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Data sheet status

Document status ^{[1][2]}	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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Revision history

Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
BFQ19_N_3	20070928	Product data sheet	-	BFQ19_CNV_2
Modifications:	• Fig. 1 and package outline updated			
BFQ19_CNV_2	19950901	Product specification	-	-

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